TSMC-01-167CB

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January 5, 2004

o: Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572

28 Davis Avenue

Poughkeepsie, N.Y. 12603

Subject:

Serial No. 10/696,432 10/29/03

Ying-Lang Wang et al.

IMPROVED CMP PROCESS LEAVING NO RESIDUAL OXIDE LAYER OR SLURRY PARTICLES

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56. Copies of each document is included herewith.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on January 17, 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

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- U.S. Patent 5,662,769 to Schonauer et al., "Chemical Solutions for Removing Metal-Compound Contaminants from Wafers After CMP and the Method of Wafer Cleaning," discloses a tungsten CMP process and post clean.
- U.S. Patent 6,165,956 to Zhang et al., "Methods and Apparatus for Cleaning Semiconductor Substrates after Polishing of Copper Film," discloses a tungsten CMP together with NH4OH brushing in the background section.
- U.S. Patent 5,968,280 to Ronay, "Method for Cleaning a Surface," discloses a poly-electrolyte post CMP clean.
- U.S. Patent 5,868,863 to Hymes et al., "Method and Apparatus for Cleaning of Semiconductor Substrates Using Hydrofluoric Acid (HF)," discloses a cleaning method and apparatus using very dilute hydrofluoric acid (HF) for cleaning silicon wafers and semiconductor substrates.
- U.S. Patent 6,207,630 to Vaartstra, "Processing Compositions and Methods of Using Same," discloses compositions and methods for using such compositions in the removal of contaminants from substrates and equipment.

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Sincerely

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